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Silicon Carbide Schottky Diode

650 V, 12 A

FFSM1265A

Description

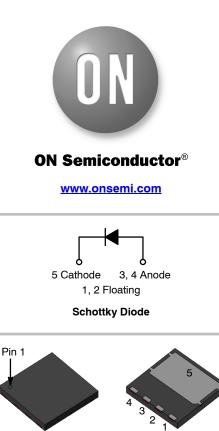
Silicon Carbide (SiC) Schottky Diodes use a completely new technology that provides superior switching performance and higher reliability compared to Silicon. No reverse recovery current, temperature independent switching characteristics, and excellent thermal performance sets Silicon Carbide as the next generation of power semiconductor. System benefits include highest efficiency, faster operating frequency, increased power density, reduced EMI, and reduced system size and cost.

Features

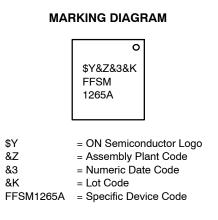
- Max Junction Temperature 175°C
- Avalanche Rated 79 mJ
- High Surge Current Capacity
- Positive Temperature Coefficient
- Ease of Paralleling
- No Reverse Recovery/No Forward Recovery
- This Device is Pb–Free, Halogen Free/BFR Free and RoHS Compliant

Applications

- General Purpose
- SMPS, Solar Inverter, UPS
- Power Switching Circuits



PQFN4 8X8, 2P (Power88) CASE 483AP



ORDERING INFORMATION

See detailed ordering and shipping information on page 2 of this data sheet.

FFSM1265A

Symbol	Parameter	Value	Unit	
V _{RRM}	Peak Repetitive Reverse Voltage	650	V	
E _{AS}	Single Pulse Avalanche Energy (Note 1)	79	mJ	
١ _F	Continuous Rectified Forward Current @ T_C < \sim	12	А	
	Continuous Rectified Forward Current @ T_C < \sim	12.5	А	
I _{F, Max}	Non-Repetitive Peak Forward Surge Current	T _C = 25°C, 10 μs	700	А
		T _C = 150°C, 10 μs	515	А
I _{F,SM}	Non-Repetitive Forward Surge Current	Half-Sine Pulse, t _p = 8.3 ms	63	А
I _{F,RM}	Repetitive Forward Surge Current	Half-Sine Pulse, t _p = 8.3 ms	31	А
Ptot	Power Dissipation	$T_{\rm C} = 25^{\circ}{\rm C}$	80	W
		T _C = 150°C	14	W
T _J , T _{STG}	Operating and Storage Temperature Range		–55 to +175	°C

ABSOLUTE MAXIMUM RATINGS (T_C = 25°C unless otherwise noted)

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

1. E_{AS} of 79 mJ is based on starting T_J = 25°C, L = 1 mH, I_{AS} = 12.6 A, V = 50 V.

THERMAL CHARACTERISTICS

Symbol	Parameter	Value	Unit
$R_{\theta JC}$	Thermal Resistance, Junction to Case, Max	1.87	°C/W

ELECTRICAL CHARACTERISTICS (T_C = 25°C unless otherwise noted)

Symbol	Parameter	Test Condition	Min	Тур	Max	Unit
V _F	Forward Voltage	I _F = 12 A, T _C = 25°C	-	1.5	1.75	V
		$I_F = 12 \text{ A}, \text{ T}_C = 125^{\circ}\text{C}$	-	1.6	2.0	
		I _F = 12 A, T _C = 175°C	-	1.72	2.4	
I _R	Reverse Current	$V_{R} = 650 \text{ V}, \text{ T}_{C} = 25^{\circ}\text{C}$	-	-	200	μΑ
		$V_{R} = 650 \text{ V}, \text{ T}_{C} = 125^{\circ}\text{C}$	-	-	400	
		$V_{R} = 650 \text{ V}, \text{ T}_{C} = 175^{\circ}\text{C}$	-	-	600	
Q _C	Total Capacitive Charge	V = 400 V	-	40	-	nC
С	Total Capacitance	V _R = 1 V, f = 100 kHz	-	665	-	pF
		V _R = 200 V, f = 100 kHz	-	74	-	
		V _R = 400 V, f = 100 kHz	-	54	-	

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

PACKAGE MARKING AND ORDERING INFORMATION

Part Numbe	r Top	Marking	Package	Reel Size	Tape Width	Shipping (Qty / Packing)
FFSM1265/	A FFS	M1265A	PQFN4 8X8, 2P (Power88)	13″	13.3 mm	3000 / Tape & Reel

+For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

FFSM1265A

TYPICAL CHARACTERISTICS

(T_J = 25°C unless otherwise noted)

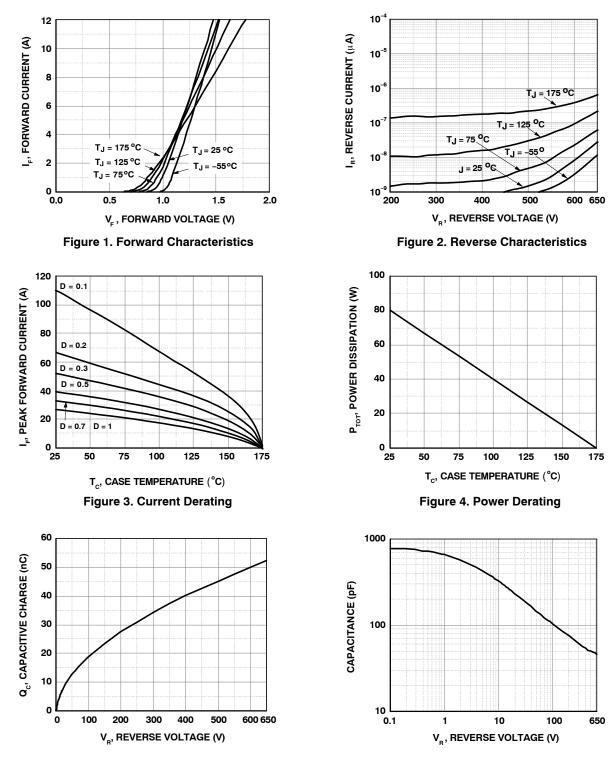


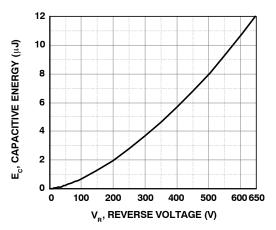
Figure 5. Capacitive Charge vs. Reverse Voltage

Figure 6. Capacitance vs. Reverse Voltage

FFSM1265A

TYPICAL CHARACTERISTICS

(T_J = 25°C unless otherwise noted)





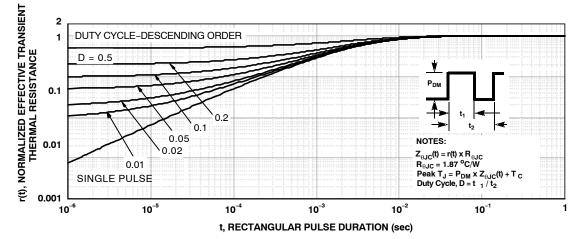
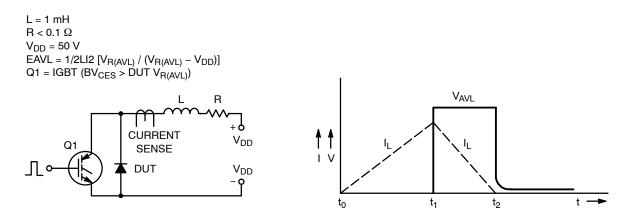


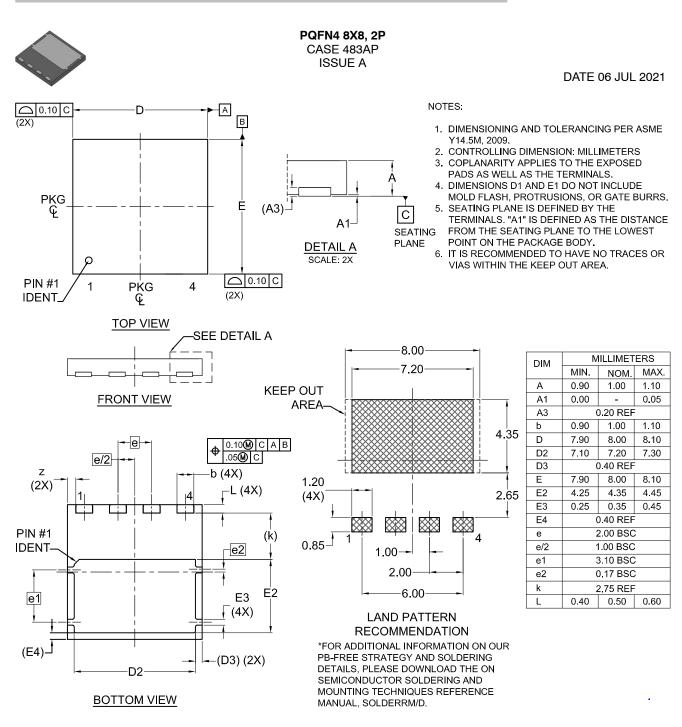
Figure 8. Junction-to-Case Transient Thermal Response Curve

TEST CIRCUIT AND WAVEFORMS









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